

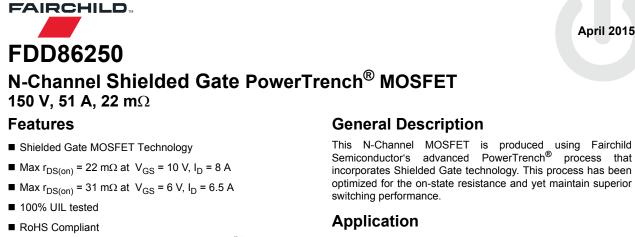
Is Now Part of



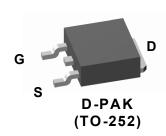
# **ON Semiconductor**®

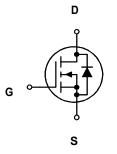
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DC - DC Conversion





## MOSFET Maximum Ratings T<sub>C</sub> = 25 °C unless otherwise noted.

Symbol	Parameter			Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage			150	V	
V <sub>GS</sub>	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous	T <sub>C</sub> = 25 °C	(Note 5)	51		
	-Continuous	T <sub>C</sub> = 100 °C	(Note 5)	27	•	
	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	8	Α	
	-Pulsed		(Note 4)	164		
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	180	mJ	
P <sub>D</sub>	Power Dissipation $T_{\rm C} = 25$ °C			132	W	
	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	3.1	vv	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C	

## **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case		0.94	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	40	C/vv

## Package Marking and Ordering Information

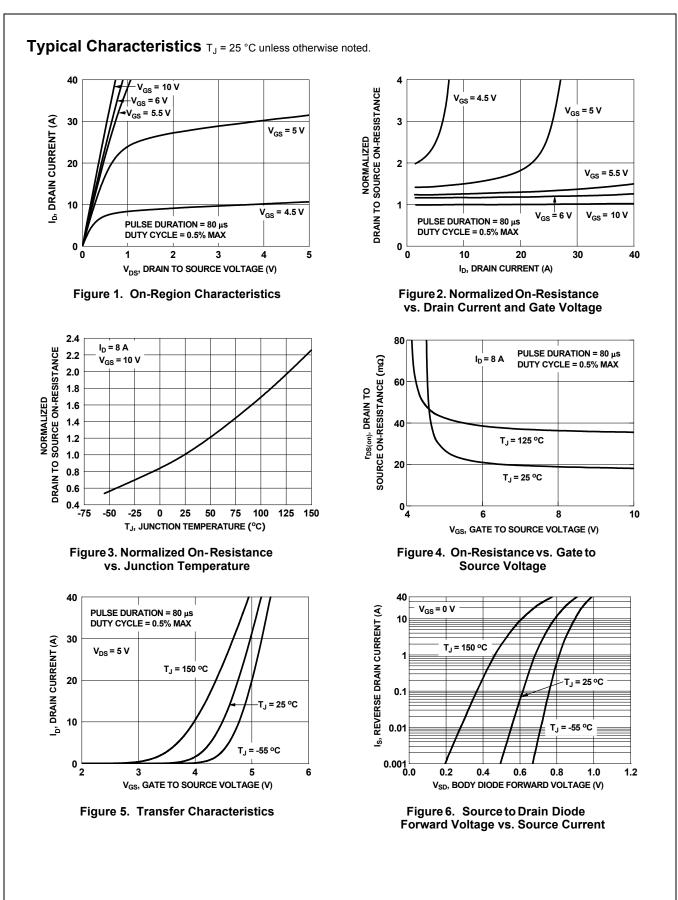
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86250	FDD86250	D-PAK(TO-252)	13 "	16 mm	2500 units

April 2015

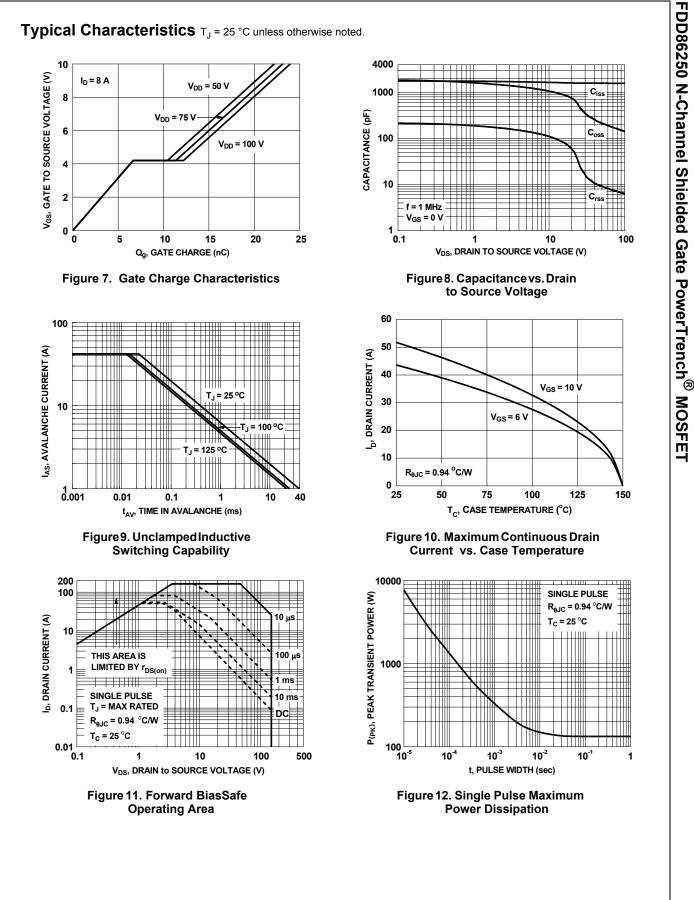
	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chara	cteristics			1	L.	
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	150	1		V
ABV <sub>DSS</sub>	Breakdown Voltage Temperature		100	106		
$\Delta T_{J}$	Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		106		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS}$ = 120 V, $V_{GS}$ = 0 V			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V			±100	nA
On Chara	cteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	2.0	2.9	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, referenced to 25 °C		-10		mV/°C
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8 A		18.4	22	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$		21.4	31	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8 A, T <sub>J</sub> = 125 °C		35.8	45	1
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 8 A		28		S
Dvnamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			1585	2110	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 75 V, V_{GS} = 0 V,$		167	225	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		7	15	pF
R <sub>g</sub>	Gate Resistance			0.6		Ω
-	g Characteristics			L		1
t <sub>d(on)</sub>	Turn-On Delay Time			11.2	20	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 75 V, I <sub>D</sub> = 8 A,		3.7	10	ns
d(off)	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		20	32	ns
t <sub>f</sub>	Fall Time			4	10	ns
Qg	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V		23	33	nC
Qg	Total Gate Charge	$V_{GS}$ = 0 V to 5 V $V_{DD}$ = 75 V,		12.8	18	nC
Q <sub>gs</sub>	Gate to Source Charge	I <sub>D</sub> = 8 A		6.7		nC
	Gate to Drain "Miller" Charge			4.7		nC
Q <sub>gd</sub>						
	urce Diode Characteristics					
Drain-Soເ		V <sub>GS</sub> = 0 V, I <sub>S</sub> = 8 A (Note 2)		0.78	1.3	V
Drain-Soເ	Source-Drain Diode Forward Voltage	$\frac{V_{GS} = 0 \text{ V}, \text{ I}_{S} = 8 \text{ A}}{V_{GS} = 0 \text{ V}, \text{ I}_{S} = 2.6 \text{ A}}  (\text{Note 2})$		0.78 0.73	1.3 1.2	V
						V ns

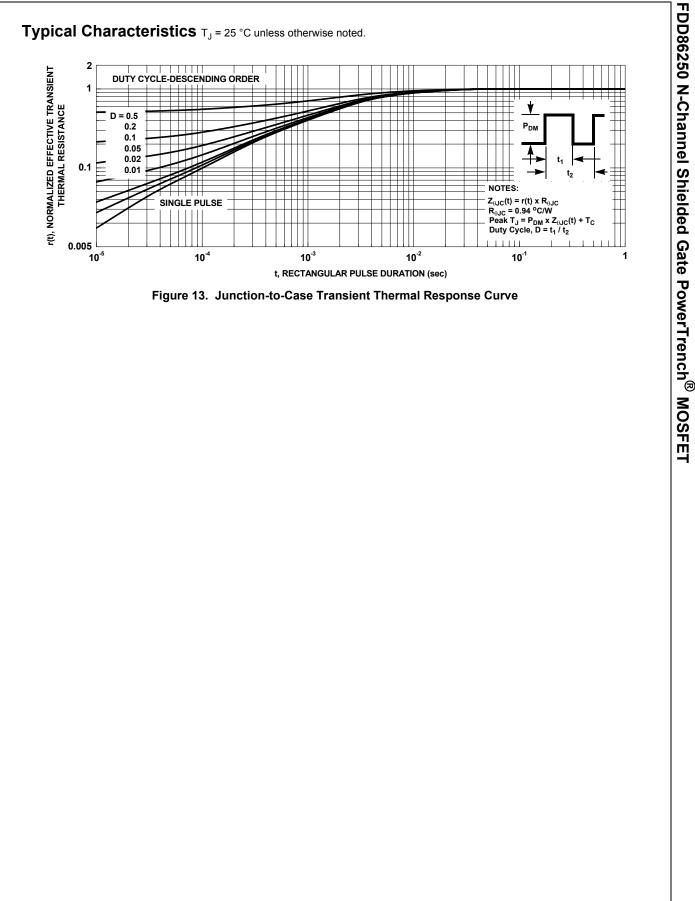
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Pulse Test: Pulse Width < 300 µs, Duty cycle < 2.0%.</li>
Starting T<sub>J</sub> = 25 °C, L = 1.0 mH, I<sub>AS</sub> = 19 A, V<sub>DD</sub> = 135 V, V<sub>GS</sub> = 10 V.
Pulsed Id please refer to Fig 11 SOA graph for more details.
Computed continuous current limited to Max Junction Temperature only, actual continuous current will be limited by thermal & electro-mechanical application board design.



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